

INFORMATION DISCLOSURE CITATION <i>(Use several sheets if necessary)</i>		Docket Number (Optional) 50478-3700		Application Number 10/591153		Filing Date 08/30/06		Group Art Unit 2826									
		Applicant(s) Hideo Nagai et al.		Filing Date 08/30/06		Group Art Unit 2826		Not yet assigned									
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U. S. PATENT DOCUMENTS																	
EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE										
/TT/		6,222,207	4.24.2001	Carter-Coman et al.													
/TT/		6,316,785	11.13.2001	Nunoue et al.													
U.S. PATENT APPLICATION PUBLICATIONS																	
EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE										
/TT/		2004-0031956	2.19.2004	Saxler													
FOREIGN PATENT DOCUMENTS																	
	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation										
							YES	NO									
/TT/		2003-110138	4.11.2003	Japan w/English Abstract			X										
/TT/		11-330552	11.30.1999	Japan w/English Abstract			X										
OTHER DOCUMENTS <i>(Including Author, Title, Date, Pertinent Pages, Etc.)</i>																	
/TT/		Yamada, Motokazu et al; InGaN-Based Near-Ultraviolet and Blue-Light-Emitting Diodes with High External Quantum Efficiency Using a Patterned Sapphire Substrate and a Mesh Electrode; Jpn. J. Appl. Phys Vol. 41 (2002) pp. L1431-L1433, Part 2, No. 12B, December 15, 2002, The Japan Society of Applied Physics.															
EXAMINER /Tan Tran/				DATE CONSIDERED 05/08/2008													
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